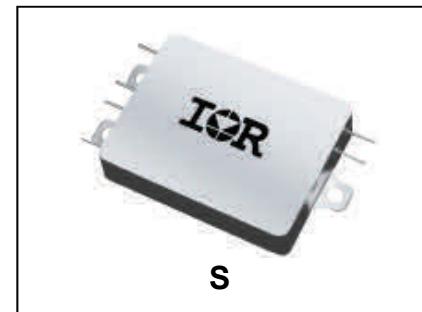


**HYBRID-HIGH RELIABILITY
RADIATION HARDENED
LOW POWER
DC-DC CONVERTER****28V Input, Single/Dual Output****Description**

The S-Series of DC-DC converters are low power radiation hardened, high reliability devices designed for hostile radiation environments such as those encountered by geostationary earth orbit satellites, deep space probes and communication systems. Features include small size, high efficiency, low weight and a high tolerance to total ionizing dose, single event effects, and environmental stresses such as temperature extremes, mechanical shock, and vibration. Extensive documentation including Radiation Susceptibility, Thermal Analysis, Stress Analysis and MTBF are available.

The converters incorporate a fixed frequency single ended forward topology with magnetic feedback and an internal EMI filter utilizing large multilayer ceramic capacitors processed per MIL-PRF-49470 for improved reliability. All models include an external inhibit port. They are encased in a hermetic 1.71" x 1.31" x 0.45" steel package and weigh less than 50 grams. The package utilizes rugged ceramic feed-through copper core pins and is hermetically sealed using parallel seam welding.

Manufactured in a facility fully qualified to MIL-PRF-38534, these converters are fabricated utilizing DLA Land and Maritime qualified processes. For available screening options, refer to device screening table in the data sheet.

Non-flight versions of the S-Series converters are available for system development purposes. Variations in electrical specifications and screening to meet custom requirements can be accommodated. Consult IR HiRel San Jose for special requirements.

Features

- Total Dose > 100 kRads(Si)
- SEE Hardened to LET up to 82 MeV.cm²/mg
- Low Weight < 50 grams
- Magnetically Coupled Feedback
- 18V to 40V Input Range
- Up to 10W Output Power
- Single and Dual Output Models Include 3.3, 5, 7, 12, 15, ±5, ±12, ±15V
- High Efficiency - to 82%
- -55°C to +125°C Operating Temperature Range
- 100MΩ @ 500VDC Isolation
- Under-Voltage Protection
- Short Circuit and Overload Protection
- External Inhibit
- Standard Microcircuit Drawings Available

Applications

- Geostationary or Low Earth Orbit Satellites
- Launch Vehicles
- Communication Systems

Circuit Description

The S-Series converters utilize a single-ended forward topology with resonant reset. The nominal switching frequency is 525 kHz. Electrical isolation and tight output regulation are achieved through the use of a magnetically coupled feedback. Voltage feed-forward with duty factor limiting provides high line rejection.

Output power is limited under any load fault condition to approximately 135% for singles and 145% for duals of rated. An overload condition causes the converter output to behave like a constant current source with the output voltage dropping below nominal. The converter will resume normal operation when the load current is reduced below the current limit point. This protects the converter from both overload and short circuit conditions. There are no latching elements included in the load fault protection circuits to eliminate the possibility of falsely triggering the protection circuits during single event radiation exposure.

An under-voltage protection circuit prohibits the converter from operating when the line voltage is too low for safe operation. The converter will not start until the line voltage rises to approximately 12V.

An external enable port is provided to control converter operation. This input is intended for operation with an open collector transistor drive or a relay closure to the input return. The pin may be left open for normal operation and has a nominal open circuit voltage of 10.5V.

Design Methodology

The S-Series was developed using a proven conservative design methodology, which includes selecting radiation tolerant, and established reliability components and fully de-rating to the requirements of MIL-STD-975 and MIL-STD-1547 except for the CDR type of capacitors, a capacitor with 50V rating is used for in-circuit voltage stress of less than 10V. Heavy de-rating of the radiation hardened power MOSFET virtually eliminates the possibility of SEGR and SEB. A magnetic feedback circuit is utilized instead of opto-couplers to minimize temperature, radiation and aging sensitivity. PSPICE was used extensively to predict and optimize circuit performance for both beginning and end-of-life. Thorough design analyses include Radiation Susceptibility (TREE), Worst Case, Stress, Thermal and Reliability (MTBF).

Specifications

Absolute Maximum Ratings		Recommended Operating Conditions		
Input voltage range		Input voltage range		+16V _{DC} to +40V _{DC}
Output power		Output power		0 to Max. Rated
Lead temperature		Operating temperature		-55°C to +125°C
Operating temperature		Operating temperature ¹		-55°C to +70°C
Storage temperature		Operating temperature ¹		-55°C to +70°C

¹ Meets de-rating per MIL-STD-975

Electrical Performance Characteristics

Parameter	Group A Subgroup	Conditions -55°C ≤ T _C ≤ +85°C V _{IN} = 28V DC ± 5%, C _L = 0 unless otherwise specified	Limits			Unit
			Min	Nom	Max	
Input voltage			18	28	40	V
Output voltage (V _{OUT})	1	I _{OUT} = 100% rated load Note 4	3.27	3.30	3.33	V
	1		4.95	5.00	5.05	
	1		6.93	7.00	7.07	
	1		11.88	12.00	12.12	
	1		14.85	15.00	15.15	
	1		±4.95	±5.00	±5.05	
	1		±11.88	±12.00	±12.12	
	1		±14.85	±15.00	±15.15	
	2,3	I _{OUT} = 100% rated load Note 4	3.230	3.370		V
	2,3		4.900	5.100		
	2,3		6.895	7.105		
	2,3		11.760	12.240		
	2,3		14.700	15.300		
	2,3		±4.900	±5.100		
	2,3		±11.760	±12.240		
	2,3		±14.700	±15.300		
Output power (P _{OUT}) All models	1,2,3	V _{IN} = 18, 28, 40 Volts, Note 2	0		10	W
Output current (I _{OUT})	1,2,3	V _{IN} = 18, 28, 40 Volts, Note 2	0		3.03	A
			0		2.00	
			0		1.43	
			0		0.83	
			0		0.67	
		Either Output, Note 3	0.16		1.60	
			0.06		0.66	
			0.05		0.54	
Line regulation (VR _{LINE}) S28XXS S28XXD	1,2,3	V _{IN} = 18, 28, 40 Volts I _{OUT} = 0, 50%, 100% rated I _{OUT} = 10%, 50%, 100% rated, Note 4	-0.5		0.5	%
Load regulation (VR _{LOAD}) S28XXS S28XXD	1,2,3	V _{IN} = 18, 28, 40 Volts I _{OUT} = 0, 50%, 100% rated I _{OUT} = 10%, 50%, 100% rated, Note 4	-1.0		1.0	%

For Notes to Electrical Performance Characteristics, refer to page 6

Electrical Performance Characteristics (continued)

Parameter	Group A Subgroup	Conditions $-55^{\circ}\text{C} \leq T_{\text{C}} \leq +85^{\circ}\text{C}$ $V_{\text{IN}} = 28\text{V DC} \pm 5\%$, $C_{\text{L}} = 0$ unless otherwise specified	Limits			Unit
			Min	Nom	Max	
Cross regulation ($V_{\text{R}_{\text{CROSS}}}$) S2805D S2812D S2815D	1,2,3	Duals only, Note 5 $V_{\text{IN}} = 18, 28, 40$ Volts	-5.0 -3.0 -3.0		5.0 3.0 3.0	%
Total regulation S2803R3S S2805S S2807S S2812S S2815S S2805D S2812D S2815D	1,2,3	$V_{\text{IN}} = 18, 28, 40$ Volts Single Output: $I_{\text{OUT}} = 0\%, 50\%, 100\%$ of rated current Note 14 Dual Output: $I_{\text{OUT}} = 10\%, 50\%, 100\%$ of rated current Notes 4, 14	-2.0 -2.0 -2.0 -2.0 -2.0 -5.0 -3.0 -3.0		2.0 2.0 2.0 2.0 2.0 5.0 3.0 3.0	%
Input current (I_{IN}) S2803R3S S2805S S2807S S2812S S2815S S2805D S2812D S2815D	1,2,3	$I_{\text{OUT}} = 0$, Pin 4 open Pin 4 shorted to pin 2			60 70 70 70 70 70 70 70 5.0	mA mA
Switching frequency (F_s)	1,2,3		475	525	575	kHz
Output ripple (V_{RIP}) S2803R3S S2805S S2807S S2812S S2815S S2805D S2812D S2815D	1,2,3	$V_{\text{IN}} = 18, 28, 40$ Volts $I_{\text{OUT}} = 100\%$ rated load Notes 4, 6			50 50 45 50 60 80 80 80	mVp-p
Efficiency (E_{FF}) S2803R3S S2805S S2807S S2812S S2815S S2805D S2812D S2815D	1,2,3	$I_{\text{OUT}} = 100\%$ rated load Note 4	68 75 76 78 77 76 76 76	73 80 81 81 82 80 81 82		%
Enable input (Inhibit Function) Open circuit voltage Drive current (sink) Voltage range	1,2,3	Note 1	9.5 -0.5		11.5 500 50	V μA V

For Notes to Electrical Performance Characteristics, refer to page 6

Electrical Performance Characteristics (continued)

Parameter	Group A Subgroup	Conditions -55°C ≤ T _c ≤ +85°C V _{IN} = 28V DC ± 5%, C _L = 0 unless otherwise specified	Limits			Unit
			Min	Nom	Max	
Current limit point Expressed as a percentage of full rated load current S2803R3S S2805S S2807S S2812S S2815S S2805D S2812D S2815D	1,2,3	V _{OUT} = 90% of Nominal, Note 4, 13	105		140	%
			105		140	
			110		144	
			105		145	
			110		146	
			105		150	
			105		160	
			105		167	
Power dissipation, load fault (P _D)	1,2,3	Short Circuit, Overload, Note 8			9.0	W
Output response to step load changes (V _{TLD})	4,5,6	Half Load to/ from Full Load, Notes 4,9	-300		300	mVpk
Recovery time, step load changes (T _{TLD})	4,5,6	Half Load to/from Full Load, Notes 4,9,10			200	μs
Output response to step line changes (V _{TLN})	4,5,6	18V to/from 40V I _{OUT} = 100% rated load, Notes 1,4,11	-300		300	mVpk
Recovery time, step line changes (T _{TLN})	4,5,6	18V to/from 40V I _{OUT} = 100% rated load, Notes 1,4,10,11			200	μs
Turn-on response Overshoot (V _{OS}) S2803R3S S2805S S2807S S2812S S2815S S2805D S2812D S2815D	4,5,6	10% Load, Full Load Notes 4,12			500	mV
Turn-on delay (T _{DLY})					600	
					750	
					1400	
					1650	
					600	
					1400	
					1500	
					10	ms
Capacitive load (C _L) S2803R3S S2805S S2807S S2812S S2815S S2805D S2812D S2815D	1	I _{OUT} = 100% rated load No effect on DC performance Notes 1, 4, 7 Each output on duals			2200	μF
					1000	
					750	
					180	
					120	
					500	
					90	
					60	

For Notes to Electrical Performance Characteristics, refer to page 6

Electrical Performance Characteristics (continued)

Parameter	Group A Subgroup	Conditions $-55^{\circ}\text{C} \leq T_c \leq +85^{\circ}\text{C}$ $V_{IN} = 28\text{V DC} \pm 5\%$, $C_L = 0$ unless otherwise specified	Limits			Unit
			Min	Nom	Max	
Line rejection	1	$I_{OUT} = 100\%$ rated load DC to 50 kHz, Notes 1, 4		50		dB
Isolation	1	Input to Output or Any Pin to Case except pin 3, test @ 500VDC	100			MΩ
Device weight					50	g
MTBF		MIL-HDBK-217F2, SF, 35°C	1.5×10^6			Hours

Notes: Electrical Performance Characteristics Table

1. Parameter is tested as part of design characterization or after design changes. Thereafter, parameter shall be guaranteed to the limits specified.
2. Parameter verified during line and load regulation tests.
3. Output load current must be distributed such that at least 20% of the total load current is being provided by one of the outputs.
4. Load currents split equally between outputs on dual output models. For dual output models, the output may not meet regulation limits but the converter will not be damaged under this condition.
5. Cross regulation is measured with 20% rated load on output under test while changing the load on the other output from 20% to 80% of rated.
6. Guaranteed for a D.C. to 20 MHz bandwidth. Tested using a 20 kHz to 10 MHz bandwidth.
7. Capacitive load may be any value from 0 to the maximum limit without compromising dc performance. A capacitive load in excess of the maximum limit may interfere with the proper operation of the converter's overload protection, causing erratic behavior during turn-on.
8. Overload power dissipation is defined as the device power dissipation with the load set such that $V_{OUT} = 90\%$ of nominal.
9. Load step transition time $\geq 10 \mu\text{s}$
10. Recovery time is measured from the initiation of the transient to where V_{OUT} has returned to within $\pm 1\%$ of its steady state value
11. Line step transition time $\geq 100 \mu\text{s}$.
12. Turn-on delay time from either a step application of input power or a logic low to a logic high transition on the inhibit pin (pin 4) to the point where $V_{OUT} = 90\%$ of nominal.
13. Current limit point expressed as a percentage of full rated load current.
14. Total Regulation includes all combinations of line and load compared to the nominal output voltage. For dual models all line, load, and cross regulation conditions are tested per Note 4 and Note 5.

Radiation Performance Characteristics

Test	Conditions	Min	Typ	Unit
Total Ionizing Dose (Gamma)	MIL-STD-883, Method 1019.5 Operating bias applied during exposure, Full Rated Load, $V_{IN} = 28\text{V}$	100		kRads(Si)
Single Event Effects SEU, SEL, SEGR, SEB	Heavy ions (LET) Operating bias applied during exposure, Full Rated Load, $V_{IN} = 28\text{V}$ Test lab : Cyclotron Institute, Texas A & M University	82		MeV•cm ² /mg

IR HiRel currently does not have a DLA Land and Maritime certified Radiation Hardness Assurance Program.

Figure 1. Block Diagram - Single Output

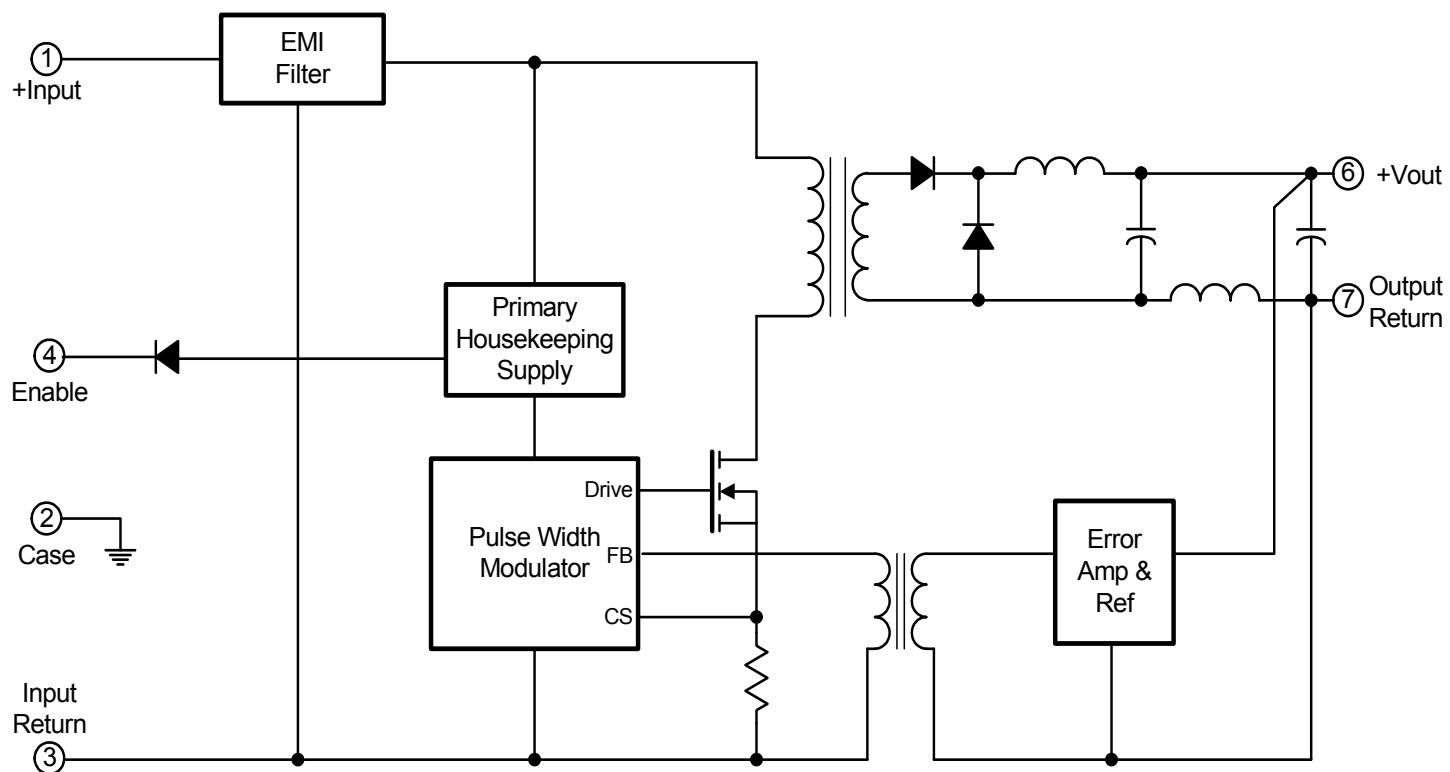
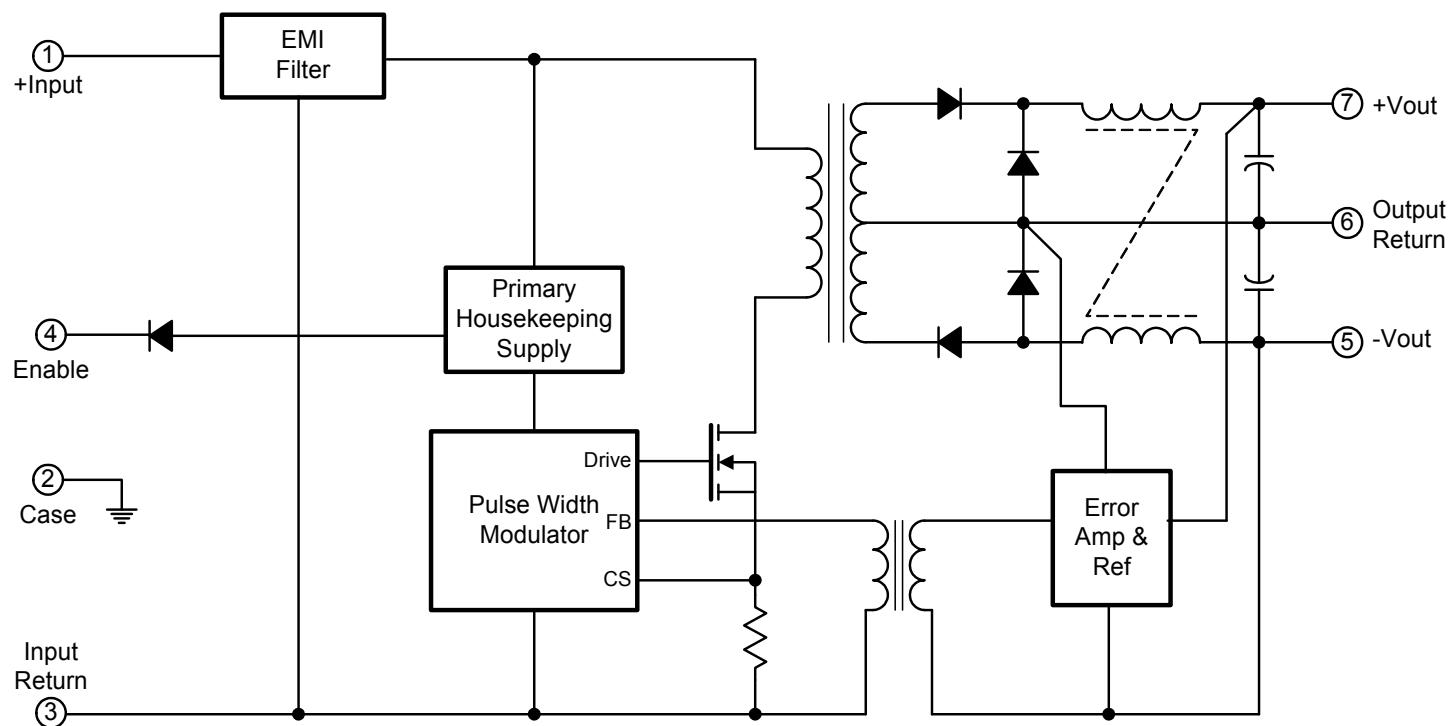
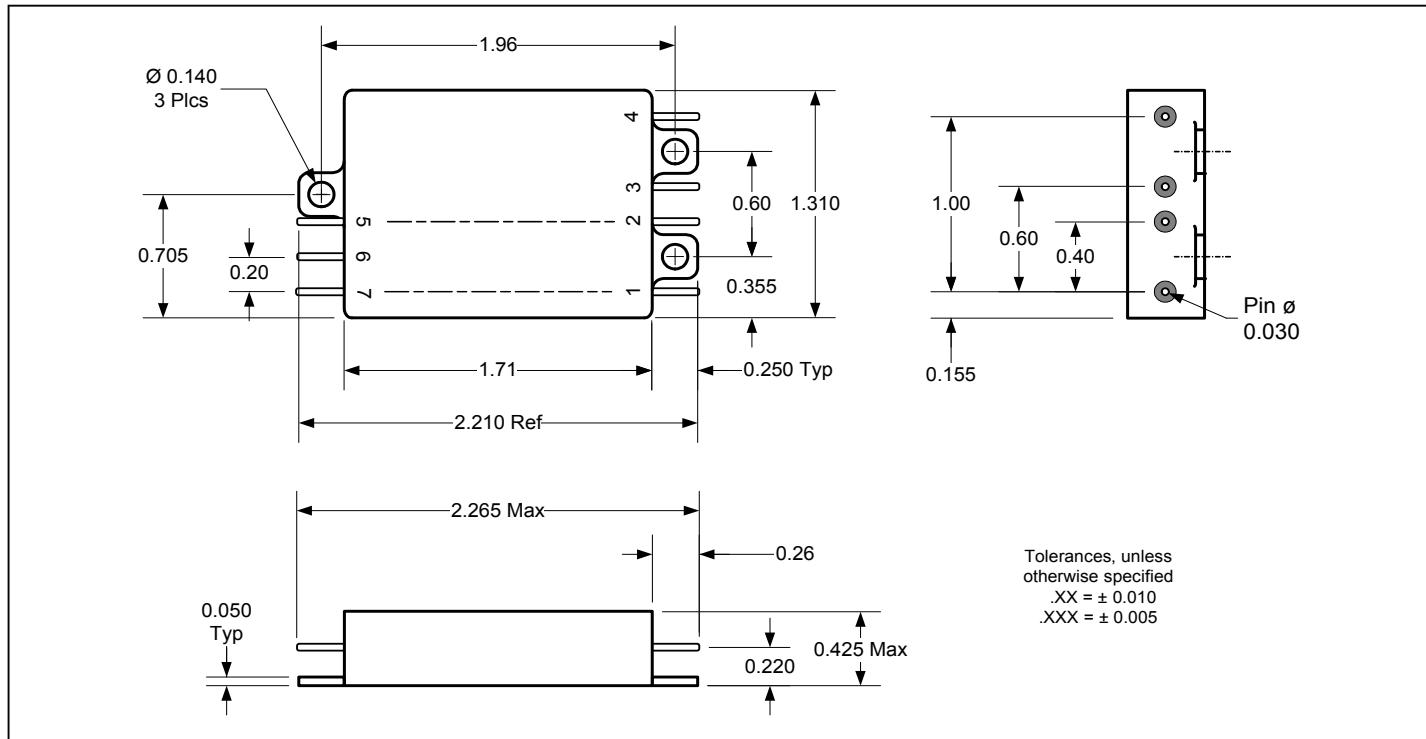


Figure 2. Block Diagram - Dual Output



Mechanical Outline



Pin Designation

Pin #	Designation (Single)	Pin #	Designation (Dual)
1	+ Vin	1	+ Vin
2	Case	2	Case
3	Input Return	3	Input Return
4	Enable	4	Enable
5	NC	5	- Vout
6	+ Vout	6	Output Return
7	Output Return	7	+ Vout

Standard Microcircuit Drawing Equivalence Table

Standard Microcircuit Drawing Number	IR Standard Part Number
5962-04238	S2803R3S
5962-04239	S2805S
5962-13216	S2807S
5962-04240	S2812S
5962-04241	S2815S
5962-04242	S2805D
5962-04243	S2812D
5962-04244	S2815D

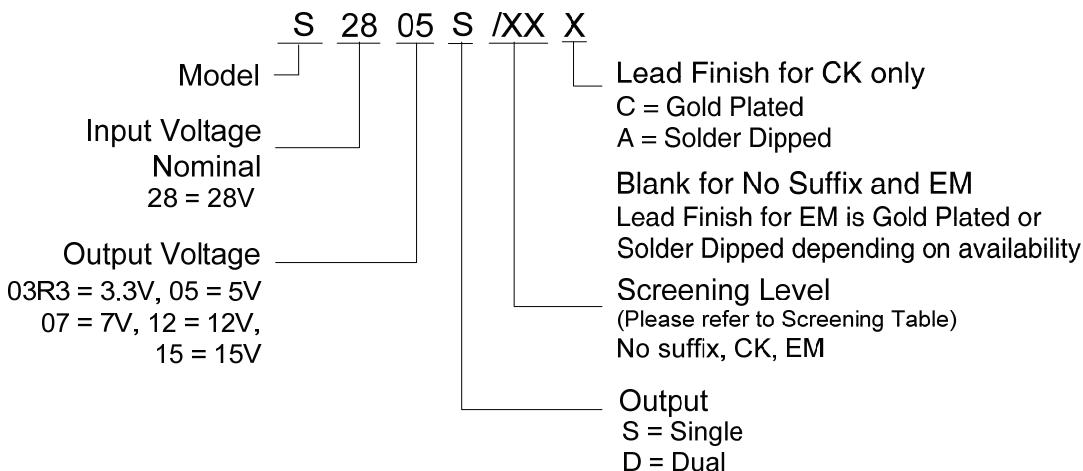
Device Screening

Requirement	MIL-STD-883 Method	No Suffix ②	CK②	EM ③
Temperature Range	—	-55°C to +85°C	-55°C to +85°C	-55°C to +85°C
Element Evaluation	MIL-PRF-38534	Class K	Class K	N/A
Non-Destructive Bond Pull	2023	Yes	Yes	N/A
Internal Visual	2017	Yes	Yes	①
Temperature Cycle	1010	Cond C	Cond C	Cond C
Constant Acceleration	2001, Y1 Axis	3000 Gs	3000 Gs	3000 Gs
PIND	2020	Cond A	Cond A	N/A
Burn-In	1015	320 hrs @ 125°C (2 x 160 hrs)	320 hrs @ 125°C (2 x 160 hrs)	48 hrs @ 125°C
Final Electrical (Group A)	MIL-PRF-38534 & Specification	-55°C, +25°C, +85°C	-55°C, +25°C, +85°C	-55°C, +25°C, +85°C
PDA	MIL-PRF-38534	2%	2%	N/A
Seal, Fine and Gross	1014	Cond A, C	Cond A, C	Cond A
Radiographic	2012	Yes	Yes	N/A
External Visual	2009	Yes	Yes	①

Notes:

- ① Best commercial practice.
- ② CK is a DLA Land and Maritime (formerly DSCL) part marking used to designate a Class K compliant hybrid. The CK marking does not indicate the hybrid is radiation certified. No suffix is a radiation rated device but not available as a DLA qualified SMD per MIL-PRF-38534.
- ③ Any Engineering Model (EM) build with the "EM" Suffix shall only be form, fit and functional equivalent to its Flight Model (FM) counterpart, and it may not meet the radiation performance. The EM Model shall not be expected to comply with MIL-PRF-38534 flight quality/workmanship standards, and configuration control. An EM build may use electrical equivalent commercial grade components. IR HiRel will provide a list of non-compliance items upon request.

Part Numbering



IMPORTANT NOTICE

The information given in this document shall be in no event regarded as guarantee of conditions or characteristic. The data contained herein is a characterization of the component based on internal standards and is intended to demonstrate and provide guidance for typical part performance. It will require further evaluation, qualification and analysis to determine suitability in the application environment to confirm compliance to your system requirements.

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